Tuning the magic angle of twisted bilayer graphene at the exit of a waveguide

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We introduce a new method that allows reducing the strength of the interlayer couplings in few-layer van der Waals heterostructures by irradiating them with longitudinal waves of light. As a specific application, we consider twisted bilayer graphene and show that we can tune the magic angles in a controlled manner. According to Maxwell’s equations, the electromagnetic fields associated with light in free space do not possess longitudinal components. However, this can be circumvented by imposing suitable boundary conditions in space as in metallic waveguides, which can generate electric fields with longitudinal components (transverse magnetic modes (TM)). We propose to place twisted bilayer graphene at a specific location at the exit of a waveguide, such that it is subjected to purely longitudinal components of a TM wave. We derive an analytic model to predict the magic angle as a function of the drive and waveguide parameters. This approach could be employed in experiments to tune the Fermi velocity in experiments and explore the strongly correlated physics in-situ.

Introduction. Van der Waals heterostructures are flexible platforms to engineer systems with designer properties because they are not constrained by the chemistry of the two-dimensional materials composing the system.12 The properties of such heterostructures can be tuned with the knobs provided by the layer material choice, temperature, pressure, applied fields, time-dependent drives, etc. Recent experimental advances made possible the introduction of a new knob: a relative twist angle between the layers. In particular, twisted bilayer graphene (TBG) has emerged as a controllable platform for the study of strongly correlated physics.24,25 Specifically, TBG exhibits an insulating state at half-filling driven by electron-electron interactions,24,25 which can transition into superconducting1, and ferromagnetic26 states at specific filling factors.

One of the main parameters that controls the location of the magic angle is the interlayer tunneling amplitude. Fine tuning of the rotation angle represents one of the main challenges for the experimental realization of strongly correlated states, since the band structure is very sensitive to small changes in this angle. Recent theoretical studies suggested the possibility to overcome small misalignments away from the magic angle by applying uniaxial pressure.27,28 Furthermore, experiments have already shown that hydrostatic pressure can increase the tunneling amplitude between the layers and lead to strongly correlated states in samples otherwise dominated by the kinetic energy.29,30 This procedure addresses the layer misalignment issue for samples with angles larger than the magic angle. However, no controlled scheme has been proposed to date to reduce the tunneling amplitude between the layers and decrease the magic angle.

Traditional Floquet engineering in free space using circularly-polarized light allows to break time reversal symmetry, induce non-trivial gaps in the quasienergy spectrum and leads to rich topological phase diagrams by modifying the intralayer hopping amplitude.31,32 Recently, this traditional Floquet protocol was applied to twisted bilayer graphene. It allows to induce topological transitions at large twist angles using high-frequency drives,33 tune the bandwidth of the energy levels near charge neutrality and induced induce a transition to a Chern insulating phase with Chern number \( C = 4 \) in the high-frequency regime, and induce flat bands using near-infrared light in a wide range of twist angles.34 Despite the high degree of tunability induced by the Floquet protocols, the interlayer tunneling amplitude is not easily affected.

In this work, we demonstrate that in a waveguide a transverse magnetic (TM) mode can directly couple to the inter-layer tunneling in few-layer van der Waals systems. The intensity and frequency of the drive can then be used to modify the tunneling strength without additional not desired effects. Therefore, in the context of twisted bilayer graphene, Floquet drives using light con-
defined inside a waveguide allows to decrease the magic angle, providing the knob in this missing direction. Although this work focuses on twisted bilayer graphene, the drive protocol we propose is general and can be applied to other low-dimensional systems to tune the strength of interlayer couplings. This is useful because a change in strength of interlayer couplings can have many interesting consequences. For example, a theoretical work suggests that MoS$_2$ bilayers can host Moire quantum wells with an energy level structure sensitive to interlayer coupling strength.

In general, our approach increases the degree in which the parameters of low-dimensional systems can be modified in out-of-equilibrium settings. It allows to directly tune the Fermi velocity of the quasienergy spectrum and it increases the degree in which the parameters of low-dimensional systems can be modified in a controlled way. In the following, we discuss the consequences of Floquet drives in waveguides on twisted bilayer graphene. However, we stress that this protocol can be implemented in other low-dimensional van der Waals heterostructures.

**Static model.** When two graphene layers are misaligned with respect to each other by a rotation, a moire pattern emerges with a tunneling amplitude between the layers that is dominated by processes at lattice sites located directly on top of each other. The low-energy effective Hamiltonian for static twisted bilayer graphene (TBG) is

\[
H = \begin{pmatrix}
(h(-\theta/2, k - \kappa_+) & T(x) \\
T^\dagger(x) & h(\theta/2, k - \kappa_-)
\end{pmatrix},
\]

which describes two stacked graphene layers that are twisted with respect to each other at an angle $\theta$. Each graphene layer is described by the Hamiltonian

\[
h(\theta, k) = \gamma \begin{pmatrix} 0 & f(R(\theta)|k) \\ f^*(R(\theta)|k) & 0 \end{pmatrix},
\]

where $k$ is the in-plane momentum. $R(\theta)$ corresponds to a rotation around the axis perpendicular to the graphene sheets by an angle $\theta$, and $f(k) = e^{-2ia_0k_y/3} + 2e^{ia_0k_y/3} \sin (a_0k_x/\sqrt{3} - \pi/6)$ is the intra-layer hopping matrix expressed in momentum space. In each layer, we shift the momenta by the lattice vectors $\kappa_{\pm} = k_0 (-\sqrt{3}/2, \pm 1/2)$. Here $k_0 = k_D \sin (\theta/2)$ and $k_D = \delta \pi/(3a_0)$ defines the angle dependent momentum scale of the bilayer system. The tunneling processes between the layers are approximated by $T(x) = \sum_{i=1}^{m_{BZ}} e^{-ib_i \cdot x} T_i$, where the matrix structure is given by

\[
T_n = w_0 l_2 + w_1 \left( \cos \left( \frac{2\pi n}{3} \right) \sigma_1 + \sin \left( \frac{2\pi n}{3} \right) \sigma_2 \right),
\]

where $b_{\pm} = k_0 (\pm \sqrt{3}, 3)/2$ are the reciprocal moire lattice vectors and $b_0 = (0, 0)$ is introduced to write $T(x)$ compactly.

In bilayer graphene, some stacking configurations are energetically more favorable over others. Particularly, AB/BA stacking, where half the atoms of the upper graphene layer lie on top of the empty hexagon centers of the lower layer, is favored over AA stacked regions where the upper layer is directly on top the lower layer. This energy-dependent stacking configuration leads to relaxation effects in twisted bilayer graphene, where AB/BA regions are favored over AA regions. We take this effect and corrugation into account through the additional parameter $w_1$ in the tunneling amplitude. This can be understood recognizing that the parameter $w_0$ enters the Hamiltonian in the form of a AA stacking hopping. On the other hand, $w_1$ enters as hopping in bilayer graphene AB/BA configuration. Therefore, $w_1/w_0 > 1$ corresponds to systems where AB-stacked regions are favored. Then, the ratio $w_1/w_0$ can be used to model systems with larger or smaller AB/BA regions.

**Driving protocol.** We now place the twisted bilayer graphene sample at the exit of a metallic wave-
uide, as sketched in Fig. 1. The transverse magnetic modes (TM) are derived from the vector potential $A = \tilde{\zeta}A \sin (m\pi x/a) \sin (n\pi y/b) \Re(e^{-ik_z z - i\Omega t})$, where $k_z = \sqrt{k^2 - (m\pi/a)^2 - (n\pi/b)^2}$ is the wavenumber in the $z$-direction, $k^2 = \Omega^2 \mu \varepsilon$, $\mu$ is the permeability constant of the insulator inside the waveguide, and $\varepsilon$ is the dielectric constant. The waveguide cut-off frequency is given by $\Omega_c = 1/(\mu \varepsilon) \sqrt{(m\pi/a)^2 + (n\pi/b)^2}$. A full derivation and the full electric and magnetic fields inside the waveguide are listed in the appendix A.

The maxima of the sine functions are ideal locations to place the TBG sheet because the field has a maximum amplitude $A$ at these locations and because the vector potential is constant to second order in the $x$, $y$ directions. Taking $A = A \Re(e^{-ik_z z - i\Omega t})\tilde{\zeta}$ therefore is a good approximation if the sample is small compared to the waveguide dimensions $a$, $b$. At the tight binding level, $A$ enters the Hamiltonian through the hopping elements via the Peierls substitution $t_{ij} \rightarrow t_{ij} \exp \left(-i \int_{r_i}^{r_j} A \cdot dl\right)$, where the line integral is associated with the interlayer hopping direction in real space and $r_i$ labels site $i$. The vector potential we consider only has a component in $z$-direction and therefore only influences interlayer hopping amplitudes $w_i$. For computational simplicity, we will assume that the exit of the cavity is at $z = 0$ and that the twisted bilayer graphene sheet is placed at such a location. We note that the coupling of the longitudinal vector potential is not particular of twisted bilayer graphene and applies to other van der Waals heterostructures.

In an idealized scenario, the additional phase factor in the tunneling amplitude is uniform across the sample. However, lattice relaxation effects and surface roughness introduce a position dependence to the phase due to different layer separation. An exact treatment of such a complicated scenario is not the purpose of this work. In order to simplify the picture and make analytic progress, let us recall that relaxation effects lead to two different order to simplify the picture and make analytic progress, we note that the coupling of the longitudinal vector potential is not particular of twisted bilayer graphene and applies to other van der Waals heterostructures.

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\[ \theta_n = \frac{w_1 J_0(|a_{AB}|)}{v_F k_D \alpha_n}. \] (8)

Therefore, the degree of tunability of the hopping amplitude depends on the range of values \( \eta \equiv (e/\hbar) a_{AB} A \) can take in experiments, where we reintroduced \( \hbar \) and \( e \). In terms of the electric field amplitude, we have \( \eta \equiv e a_{AB} E/(\hbar \Omega) \). Then, in a pump-probe setup, with a pump drive frequency \( \Omega = 725 \) THz (~3 eV, in the range of violet light), laser fluence of 4 mJ/cm\(^2\), and typical pulse duration \( \tau = 0.1 \) ps, we obtain \( \eta \approx 0.4 \), which leads to \( \theta_F/\theta \approx 0.96 \). The pump frequency was chosen to be larger than the bandwidth, which is approximately the point where a high-frequency approximation starts breaking down.\(^{23,24}\) This value can be further tuned by changing the permittivity inside the cavity. A waveguide of size of the order of \( a = 1 \) mm can support frequencies as small as 1 THz when the filling insulator is air. Therefore, the high-frequency regime necessary for making waveguides in the design of Floquet engineering protocols will increase the range of parameters that can be modified in out-of-equilibrium settings.

In figure 3, we plot the Fermi-velocity of the lowest band \( \epsilon_k^{(1)} \)

\[ v = \sqrt{\left(\partial_{k_x} \epsilon_k^{(1)}\right)^2 + \left(\partial_{k_y} \epsilon_k^{(1)}\right)^2}\kappa_+ \] (9)

near \( \kappa_+ \) as a function of parameter \( \alpha \). The quasi-energies were calculated using the extended space representation of the Floquet Hamiltonian.\(^{25}\)

We find that the points where the Fermi velocity vanishes, and where we have flat bands is shifted to larger values of \( \alpha \), or smaller angles \( \theta \). In the inset, we show that the position of the flat bands for the first magic angle has shifted to \( \tilde{\alpha} = 0.608 \). This shift is a 4% change in the magic angle, and in good agreement with our analytical estimates.\(^{26}\) The lowest magic angle as function of the driving strength is plotted in figure 4 for a maximum value of \( \eta \) which could be reached with a short pump pulse of \( \tau = 0.05 \) ps and drive frequency \( \Omega = 620 \) THz.

**Conclusions.** We introduced a new mechanism to dynamically tune the effective interlayer tunneling amplitude in few-layer quantum materials using longitudinal electric fields available in a waveguide. This allows us to simulate some of the effects of uniaxial negative pressure in a controlled manner. We demonstrated an application of this novel drive protocol in twisted bilayer graphene, where we can effectively decrease the magic angle. The use of waveguides in the design of Floquet engineering protocols will increase the range of parameters that can be modified in out-of-equilibrium settings.

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$$\mathbf{H} = \nabla \times \mathbf{A}; \quad \partial_t \mathbf{E} = \frac{1}{\epsilon} \nabla \times \mathbf{H}$$

From here one may see that the solution for $A$ we found is enough to accommodate the boundary conditions

$$E_y(x = a) = E_x(x = a) = E_y(y = b) = E_x(y = b) = 0$$

that a rectangular metallic waveguide introduces if we choose $k_x = \frac{m\pi}{a}$ and $k_y = \frac{n\pi}{b}$. This solution is called a transverse magnetic mode (TM) of the cavity and the fields are given as

$$E_x \propto \cos\left(\frac{m\pi x}{a}\right) \sin\left(\frac{n\pi y}{b}\right) \Re(e^{-ik_z z - i\Omega t})$$
$$E_y \propto \sin\left(\frac{m\pi x}{a}\right) \cos\left(\frac{n\pi y}{b}\right) \Re(e^{-ik_z z - i\Omega t})$$
$$E_z \propto \sin\left(\frac{m\pi x}{a}\right) \sin\left(\frac{n\pi y}{b}\right) \Re(e^{-ik_z z - i\Omega t})$$
$$H_x \propto \sin\left(\frac{m\pi x}{a}\right) \cos\left(\frac{n\pi y}{b}\right) \Re(e^{-ik_z z - i\Omega t})$$
$$H_y \propto \cos\left(\frac{m\pi x}{a}\right) \sin\left(\frac{n\pi y}{b}\right) \Re(e^{-ik_z z - i\Omega t})$$
$$H_z = 0$$

At the points we want to place the twisted bilayer graphene sheets we have $\sin = 1$ and $\cos = 0$ and therefore only $E_z$ is non-zero. This coincides with the physical understanding that the effects we discuss in the paper are actually caused by the physical fields in the correct direction.

A more complete description can be found in $[58]$

Appendix B: Numerical solution of the Hamiltonian

In this appendix, we detailed the numerical implementation of the static Hamiltonian for twisted bilayer graphene. We employ the cellular method, that was first introduced in 1933 by Wigner and Seitz$[59]$. Below we give a short summary of the steps needed.

Our starting point is the Schrödinger equation for a periodic Hamiltonian

$$E \psi = H(p, x) \psi,$$  \hspace{1cm} (B1)

where $p = -i \nabla$. Since $H(p, x)$ is periodic, with the same periodicity of the lattice, it commutes with the translation operators $T_X = e^{ipX}$ for lattice vectors $X$. That is, it also fulfills the eigenvalue equation

$$T_X \psi(x) = C \psi(x),$$  \hspace{1cm} (B2)

which has the eigenvalues $C = e^{ik_X}$ and therefore one may rearrange the equation as $e^{-ik_X} \psi(x + X) = \psi(x)$. If we multiply both sides by $e^{-ik_x}$ we see that $u(x) = e^{ik_x} \psi(x)$ is periodic, which is known a Bloch's theorem. Therefore setting $\psi(x) = e^{ik_x} u(x)$ in the Schrödinger equation gives us

$$E_k u(x) = H(p + k, x) u(x),$$  \hspace{1cm} (B3)

which describes bands $E_k$ and has coordinates restricted to one lattice unit cell. The scalar product is restricted in a similar fashion. Calculating bands therefore merely amounts to writing the Hamiltonian in a plane wave basis

$$H_{nm}(k) = \frac{1}{V_{UZ}} \int_{A_{UZ}} e^{iQ \cdot \mathbf{x}} H(k, p, x) e^{-iQ \cdot \mathbf{x} \cdot p} dx,$$  \hspace{1cm} (B4)

where $A_{UZ}$ is a unit cell, $V_{UZ}$ the volume of the unit cell and $Q_{nm}$ are reciprocal lattice vectors. The integral over the $A_{UZ}$ can be performed analytically, leading to efficient implementations of the band structure calculation.